# NSN 5962-01-368-3228

Memory Microcircuit - Page 1 of 2



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## **Body Length:**

Between 1.380 inches and 1.485 inches

## Body Width:

Between 0.220 inches and 0.310 inches

## **Body Height:**

Between 0.030 inches and 0.185 inches

## **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

## Storage Tempurature Range:

-65.0/+150.0 degrees celsius

## **Features Provided:**

Bidirectional and w/enable and w/disable and electrostatic sensitive and bidirectional

#### Inclosure Material:

Ceramic

#### **Inclosure Configuration:**

Dual-in-line

#### Output Logic Form:

Complementary-metal oxide-semiconductor logic

#### Input Circuit Pattern:

23 input

## **Current Rating Per Characteristic:**

100.00 milliamperes reverse current, dc absolute

# Terminal Surface Treatment:

Solder

#### **Product Name:**

Sram

## Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

## Time Rating Per Chacteristic:

25.00 nanoseconds access

## Memory Device Type:

Ram

# Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

# Terminal Type And Quantity:

28 printed circuit

## Shelf Life:

N/a

## Unit Of Measure:

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## Demilitarization:

Yes - demil/mli

# NSN 5962-01-368-3228

Memory Microcircuit - Page 2 of 2

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